

## DC COMPONENTS CO., LTD.

### RECTIFIER SPECIALISTS

S2A THRU S2M

# TECHNICAL SPECIFICATIONS OF SURFACE MOUNT SILICON RECTIFIER VOLTAGE RANGE - 50 to 1000 Volts CURRENT - 2.0 Amperes

#### **FEATURES**

- \* Ideal for surface mounted applications
- \* Low leakage current
- \* Glass passivated junction

#### MECHANICAL DATA

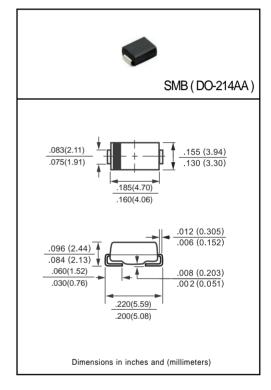
\* Case: Molded plastic

\* Epoxy: UL 94V-0 rate flame retardant \*Terminals: Solder plated, solderable per MIL-STD-750, Method 2026

\* Polarity: As marked \* Mounting position: Any \* Weight: 0.093 gram

#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.



		SYMBOL	S2A	S2B	S2D	S2G	S2J	S2K	S2M	UNITS
Maximum Recurrent Peak Reverse Voltage		VRRM	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage		VRMS	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage		VDC	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current at TA = 75 °C		lo	2.0							Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method)		IFSM	60						Amps	
Maximum Instantaneous Forward Voltage at 2.0A DC		VF	1.1						Volts	
Maximum DC Reverse Current	@Ta = 25°C	IR.	5.0							uAmps
at Rated DC Blocking Voltage	@Ta = 100°C		100							
Maximum Reverse Recovery Time (Note 3)		trr	2.5						uSec	
Typical Thermaesistance (Note 2)		RθJL	20						°C/W	
Typical Junction Capacitance (Note 1)		Cı	30						pF	
Operating and Storage Temperature Range		TJ,TSTG	-65 to + 175						۰c	

- NOTES: 1. Measured at 1 MHz and applied reverse voltage of 4.0 volts.
  - 2. Thermal Resistance (Junction to Ambient), 0.2x0.2in<sup>2</sup> (5X5mm<sup>2</sup>) copper pads to each terminal.
  - 3. Test Conditions: IF=0.5A, IR=1.0A, IRR=0.25A.







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#### RATING AND CHARACTERISTIC CURVES ( S2A THRU S2M )

FIG. 1 - TYPICAL FORWARD CURRENT DERATING CURVE AVERAGE FORWARD CURRENT, (A) Single Phase Half Wave 60Hz Resistive or Inductive Load 25 50 0 75 100 125 150 175 AMBIENT TEMPERATURE, (°C)

FIG. 2 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS 20 10 INSTANTANE US FORWARD CURRENT, (A) 4 2 1.0 .4 .2 Pulse Width=300 µ 1% Duty Cycle .1 .04 .02 .01 .6 .8 1.0 1.2 1.4 1.5 INSTANTANEOUS FORWARD VOLTAGE, (V)

FIG. 3 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT PEAK FORWARD SURGE CURRENT, (A) 100 3.3ms Single Half Sine-Wave 80 (JEDEC Method) 60 40 20 0 6 8 10 20 40 60 80 100 NUMBER OF CYCLES AT 60Hz

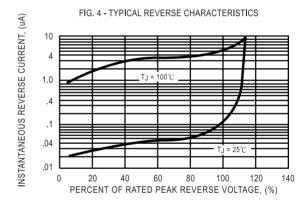


FIG. 5 - TYPICAL JUNCTION CAPACITANCE 200 JUNCTION CAPACITANCE, (pF) 100 60 40 20 10 6 4 2 1 .2 2 20 40 .1 .4 1.0 4 10 100 REVERSE VOLTAGE, (V)







